

isc Silicon PNP Power Transistor

2SB691

DESCRIPTION

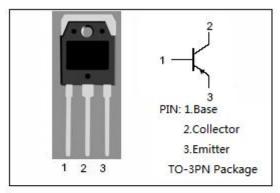
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -80V(Min)
- Good Linearity of hFE
- · Wide Area of Safe Operation
- Complement to Type 2SD727
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

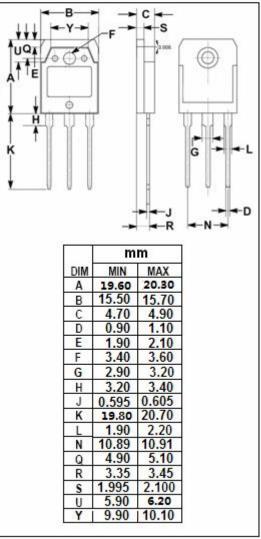


 Designed for low frequency power amplifier and power switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{СВО}	Collector-Base Voltage	-130	V	
V _{CEO}	Collector-Emitter Voltage	-80	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
Ic	Collector Current-Continuous	-5	Α	
P _C	Collector Power Dissipation @ T _C =25°C	60	W	
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	${\mathbb C}$	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -30mA; I _B = 0	-80			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = -1mA; I _E = 0	-130			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -1mA; I _C = 0	-5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -3A; I _B = -0.3A			-1.5	V
V _{BE(on)}	Base -Emitter On Voltage	I _C = -1A; V _{CE} = -5V			-1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -130V; I _E =0			-100	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C =0			-100	μА
h _{FE-1}	DC Current Gain	I _C = -1A; V _{CE} = -5V	40		200	
h _{FE-2}	DC Current Gain	I _C = -3A; V _{CE} = -5V	20			

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